

# 74HC257; 74HCT257

Quad 2-input multiplexer; 3-state

Product data sheet

## 1. General description

The 74HC257; 74HCT257 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL).

The 74HC257; 74HCT257 has four identical 2-input multiplexers with 3-state outputs, which select 4 bits of data from two sources and are controlled by a common data select input (S).

The data inputs from source 0 (1I0 to 4I0) are selected when input S is LOW and the data inputs from source 1 (1I1 to 4I1) are selected when S is HIGH. Data appears at the outputs (1Y to 4Y) in true (non-inverting) form from the selected inputs.

The 74HC257; 74HCT257 is the logic implementation of a 4-pole, 2-position switch, where the position of the switch is determined by the logic levels applied to S. The outputs are forced to a high-impedance OFF-state when  $\overline{OE}$  is HIGH.

The logic equations for the outputs are:

$$1\bar{Y} = \overline{OE} \times (1I1 \times S + 1I0 \times \bar{S})$$

$$2\bar{Y} = \overline{OE} \times (2I1 \times S + 2I0 \times \bar{S})$$

$$3\bar{Y} = \overline{OE} \times (3I1 \times S + 3I0 \times \bar{S})$$

$$4\bar{Y} = \overline{OE} \times (4I1 \times S + 4I0 \times \bar{S})$$

The 74HC257; 74HCT257 is identical to the 74HC258 but has non-inverting (true) outputs.

## 2. Features

- Non-inverting data path
- 3-state outputs interface directly with system bus
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-C exceeds 2000 V
  - ◆ MM EIA/JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$

**PHILIPS**

### 3. Quick reference data

**Table 1: Quick reference data**

$GND = 0\text{ V}$ ;  $T_{amb} = 25\text{ °C}$ ;  $t_r = t_f = 6\text{ ns}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>74HC257</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nI0, nI1 to nY	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	-	11	-	ns
	propagation delay S to nY	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	-	14	-	ns
$C_i$	input capacitance		-	3.5	-	pF
$C_{PD}$	power dissipation capacitance (per multiplexer)	$V_I = GND\text{ to }V_{CC}$	[1]	45	-	pF
<b>74HCT257</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nI0, nI1 to nY	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	-	13	-	ns
	propagation delay S to nY	$C_L = 15\text{ pF}$ ; $V_{CC} = 5\text{ V}$	-	17	-	ns
$C_i$	input capacitance		-	3.5	-	pF
$C_{PD}$	power dissipation capacitance (per multiplexer)	$V_I = GND\text{ to }V_{CC} - 1.5\text{ V}$	[1]	45	-	pF

- [1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $C_L$  = output load capacitance in pF;  
 $V_{CC}$  = supply voltage in V;  
 $N$  = number of inputs switching;  
 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

### 4. Ordering information

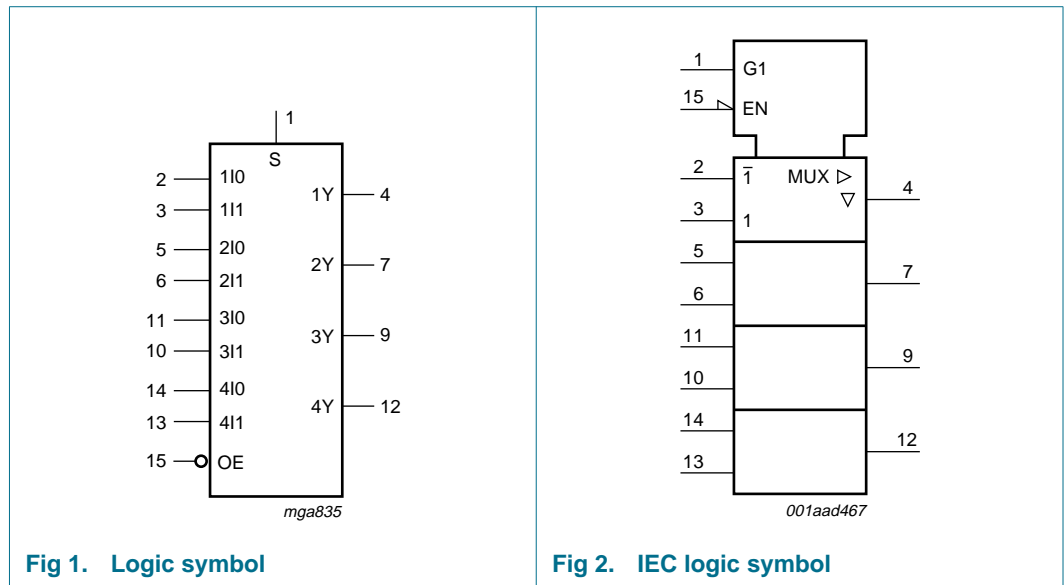
**Table 2: Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74HC257N	-40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil); long body	SOT38-1
74HC257D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC257DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HC257PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HCT257N	-40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil); long body	SOT38-1

**Table 2: Ordering information ...continued**

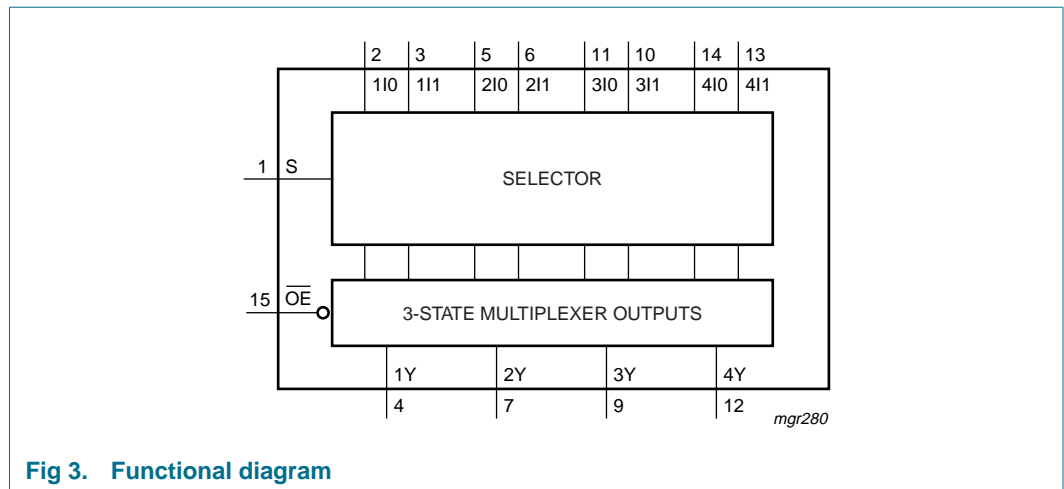
Type number	Package			Version
	Temperature range	Name	Description	
74HCT257D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT257DB	-40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HCT257PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

## 5. Functional diagram



**Fig 1. Logic symbol**

**Fig 2. IEC logic symbol**



**Fig 3. Functional diagram**

## 8. Limiting values

**Table 5: Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
$I_{IK}$	input clamping current	$V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_{OK}$	output clamping current	$V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$	-	$\pm 20$	mA
$I_O$	output current	$V_O = -0.5\text{ V}$ to $V_{CC} + 0.5\text{ V}$	-	$\pm 35$	mA
$I_{CC}$	quiescent supply current		-	+70	mA
$I_{GND}$	ground current		-	-70	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation				
	DIP16 package		[1] -	750	mW
	SO16 package		[2] -	500	mW
	SSOP16 package		[3] -	500	mW
	TSSOP16 package		[3] -	500	mW

[1] For DIP16 packages: above 70 °C,  $P_{tot}$  derates linearly with 12 mW/K.

[2] For SO16 packages: above 70 °C,  $P_{tot}$  derates linearly with 8 mW/K.

[3] For SSOP16 and TSSOP16 packages: above 60 °C,  $P_{tot}$  derates linearly with 5.5 mW/K.

## 9. Recommended operating conditions

**Table 6: Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Type 74HC257</b>						
$V_{CC}$	supply voltage		2.0	5.0	6.0	V
$V_I$	input voltage		0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$t_r, t_f$	input rise and fall times	$V_{CC} = 2.0\text{ V}$	-	-	1000	ns
		$V_{CC} = 4.5\text{ V}$	-	6.0	500	ns
		$V_{CC} = 6.0\text{ V}$	-	-	400	ns
$T_{amb}$	ambient temperature		-40	-	+125	°C
<b>Type 74HCT257</b>						
$V_{CC}$	supply voltage		4.5	5.0	5.5	V
$V_I$	input voltage		0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$t_r, t_f$	input rise and fall times	$V_{CC} = 4.5\text{ V}$	-	6.0	500	ns
$T_{amb}$	ambient temperature		-40	-	+125	°C

**Table 7: Static characteristics type 74HC257 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>				
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.33	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.33	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±5.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	80	μA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	V
		V <sub>CC</sub> = 4.5 V	3.15	-	-	V
		V <sub>CC</sub> = 6.0 V	4.2	-	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	V
		V <sub>CC</sub> = 4.5 V	-	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	-	1.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		-		
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	-	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	-	-	V
		I <sub>O</sub> = -6.0 mA; V <sub>CC</sub> = 4.5 V	3.7	-	-	V
		I <sub>O</sub> = -7.8 mA; V <sub>CC</sub> = 6.0 V	5.2	-	-	V
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		-		
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.4	V
		I <sub>O</sub> = 7.8 mA; V <sub>CC</sub> = 6.0 V	-	-	0.4	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>O</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 6.0 V	-	-	±10.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 6.0 V	-	-	160	μA

**Table 8: Static characteristics type 74HCT257**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = 25 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = -20 μA	4.4	4.5	-	V
		I <sub>O</sub> = -6 mA	3.98	4.32	-	V

**Table 8: Static characteristics type 74HCT257 ...continued**  
 At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = 20 μA	-	0	0.1	V
		I <sub>O</sub> = 6.0 mA	-	0.15	0.26	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±0.1	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±0.5	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	8.0	μA
ΔI <sub>CC</sub>	additional quiescent supply current (per input pin)	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		nI0 input	-	40	144	μA
		nI1 input	-	40	144	μA
		$\overline{\text{OE}}$ input	-	135	486	μA
		S input	-	70	252	μA
C <sub>i</sub>	input capacitance		-	3.5	-	pF
<b>T<sub>amb</sub> = -40 °C to +85 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = -20 μA	4.4	-	-	V
		I <sub>O</sub> = -6 mA	3.84	-	-	V
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = 20 μA	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	-	0.33	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±5.0	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	80	μA
ΔI <sub>CC</sub>	additional quiescent supply current (per input pin)	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		nI0 input	-	-	180	μA
		nI1 input	-	-	180	μA
		$\overline{\text{OE}}$ input	-	-	608	μA
		S input	-	-	315	μA
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	V
V <sub>OH</sub>	HIGH-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = -20 μA	4.4	-	-	V
		I <sub>O</sub> = -6 mA	3.7	-	-	V

**Table 8: Static characteristics type 74HCT257 ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>OL</sub>	LOW-state output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V				
		I <sub>O</sub> = 20 μA	-	-	0.1	V
		I <sub>O</sub> = 6.0 mA	-	-	0.4	V
I <sub>LI</sub>	input leakage current	V <sub>I</sub> = V <sub>CC</sub> or GND; V <sub>CC</sub> = 5.5 V	-	-	±1.0	μA
I <sub>OZ</sub>	OFF-state output current	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 5.5 V; V <sub>O</sub> = V <sub>CC</sub> or GND per input pin; other inputs at V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A	-	-	±10	μA
I <sub>CC</sub>	quiescent supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	160	μA
ΔI <sub>CC</sub>	additional quiescent supply current (per input pin)	V <sub>I</sub> = V <sub>CC</sub> - 2.1 V; other inputs at V <sub>CC</sub> or GND; V <sub>CC</sub> = 4.5 V to 5.5 V; I <sub>O</sub> = 0 A				
		nI0 input	-	-	196	μA
		nI1 input	-	-	196	μA
		$\overline{OE}$ input	-	-	662	μA
		S input	-	-	343	μA

## 11. Dynamic characteristics

**Table 9: Dynamic characteristics type 74HC257**

Voltages are referenced to GND (ground = 0 V); C<sub>L</sub> = 50 pF, unless otherwise specified.

For test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>T<sub>amb</sub> = 25 °C</b>							
t <sub>PHL</sub> , t <sub>PLH</sub>	propagation delay nI0 to nY or nI1 to nY	see <a href="#">Figure 6</a>					
		V <sub>CC</sub> = 2.0 V	-	36	110	ns	
		V <sub>CC</sub> = 4.5 V	-	13	22	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	11	-	ns	
	propagation delay S to nY	see <a href="#">Figure 6</a>					
		V <sub>CC</sub> = 2.0 V	-	47	150	ns	
		V <sub>CC</sub> = 4.5 V	-	17	30	ns	
		V <sub>CC</sub> = 5.0 V; C <sub>L</sub> = 15 pF	-	14	-	ns	
t <sub>PZH</sub> , t <sub>PZL</sub>	3-state output enable time $\overline{OE}$ to nY	see <a href="#">Figure 7</a>					
		V <sub>CC</sub> = 2.0 V	-	33	150	ns	
		V <sub>CC</sub> = 4.5 V	-	12	30	ns	
		V <sub>CC</sub> = 6.0 V	-	10	26	ns	
	3-state output disable time $\overline{OE}$ to nY	see <a href="#">Figure 7</a>					
		V <sub>CC</sub> = 2.0 V	-	41	150	ns	
		V <sub>CC</sub> = 4.5 V	-	15	30	ns	
		V <sub>CC</sub> = 6.0 V	-	12	26	ns	

**Table 9: Dynamic characteristics type 74HC257 ...continued**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF, unless otherwise specified.

For test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{PZH}$ , $t_{PZL}$	3-state output enable time $\overline{OE}$ to nY	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	-	225	ns
		$V_{CC} = 4.5$ V	-	-	45	ns
		$V_{CC} = 6.0$ V	-	-	38	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time $\overline{OE}$ to nY	see <a href="#">Figure 7</a>				
		$V_{CC} = 2.0$ V	-	-	225	ns
		$V_{CC} = 4.5$ V	-	-	45	ns
		$V_{CC} = 6.0$ V	-	-	38	ns
$t_{THL}$ , $t_{TLH}$	output transition time	see <a href="#">Figure 6</a>				
		$V_{CC} = 2.0$ V	-	-	90	ns
		$V_{CC} = 4.5$ V	-	-	18	ns
		$V_{CC} = 6.0$ V	-	-	15	ns

[1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

**Table 10: Dynamic characteristics type 74HCT257**

Voltages are referenced to GND (ground = 0 V);  $C_L = 50$  pF, unless otherwise specified.

For test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b><math>T_{amb} = 25</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nI0 to nY or nI1 to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 4.5$ V	-	16	30	ns
		$V_{CC} = 5.0$ V; $C_L = 15$ pF	-	13	-	ns
	propagation delay S to nY	see <a href="#">Figure 6</a>				
		$V_{CC} = 4.5$ V	-	20	35	ns
		$V_{CC} = 5.0$ V; $C_L = 15$ pF	-	17	-	ns
$t_{PZH}$ , $t_{PZL}$	3-state output enable time $\overline{OE}$ to nY	$V_{CC} = 4.5$ V; see <a href="#">Figure 7</a>	-	15	30	ns
$t_{PHZ}$ , $t_{PLZ}$	3-state output disable time $\overline{OE}$ to nY	$V_{CC} = 4.5$ V; see <a href="#">Figure 7</a>	-	16	30	ns
$t_{THL}$ , $t_{TLH}$	output transition time	$V_{CC} = 4.5$ V; see <a href="#">Figure 6</a>	-	5	12	ns
<b><math>T_{amb} = -40</math> °C to <math>+85</math> °C</b>						
$t_{PHL}$ , $t_{PLH}$	propagation delay nI0 to nY or nI1 to nY	$V_{CC} = 4.5$ V; see <a href="#">Figure 6</a>	-	-	38	ns
	propagation delay S to nY	$V_{CC} = 4.5$ V; see <a href="#">Figure 6</a>	-	-	44	ns

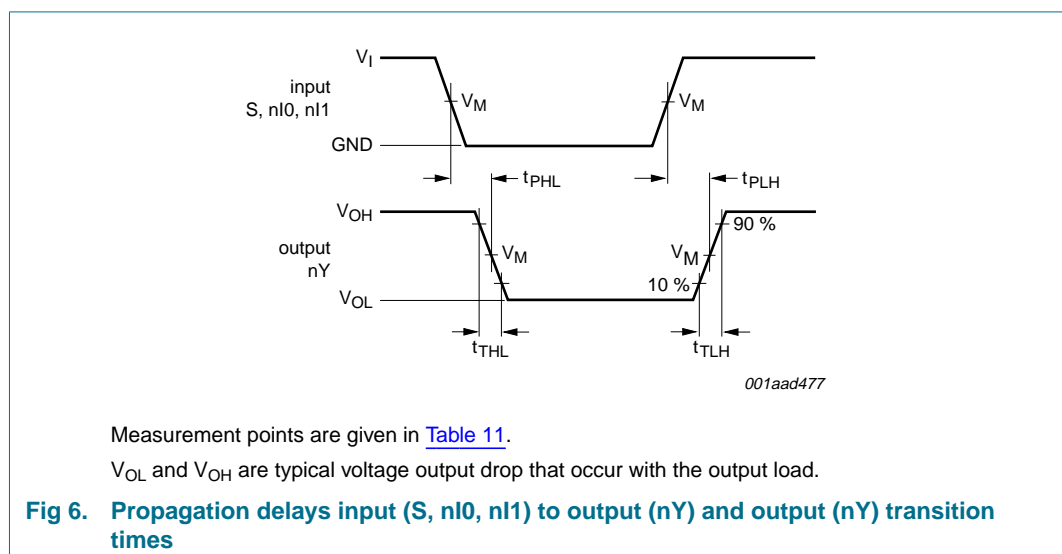


**Table 10: Dynamic characteristics type 74HCT257 ...continued**  
 Voltages are referenced to GND (ground = 0 V);  $C_L = 50 \text{ pF}$ , unless otherwise specified.  
 For test circuit see [Figure 8](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{PZH}, t_{PZL}$	3-state output enable time $\overline{OE}$ to nY	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 7</a>	-	-	38	ns
$t_{PHZ}, t_{PLZ}$	3-state output disable time $\overline{OE}$ to nY	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 7</a>	-	-	38	ns
$t_{THL}, t_{TLH}$	output transition time	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 6</a>	-	-	15	ns
<b><math>T_{amb} = -40 \text{ }^\circ\text{C to } +125 \text{ }^\circ\text{C}</math></b>						
$t_{PHL}, t_{PLH}$	propagation delay nI0 to nY or nI1 to nY	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 6</a>	-	-	45	ns
	propagation delay S to nY	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 6</a>	-	-	53	ns
$t_{PZH}, t_{PZL}$	3-state output enable time $\overline{OE}$ to nY	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 7</a>	-	-	45	ns
$t_{PHZ}, t_{PLZ}$	3-state output disable time $\overline{OE}$ to nY	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 7</a>	-	-	45	ns
$t_{THL}, t_{TLH}$	output transition time	$V_{CC} = 4.5 \text{ V}$ ; see <a href="#">Figure 6</a>	-	-	18	ns
$C_{PD}$	power dissipation capacitance (per multiplexer)	$V_I = \text{GND to } V_{CC}$	[1]	45	-	pF

- [1]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$  where:  
 $f_i$  = input frequency in MHz;  
 $f_o$  = output frequency in MHz;  
 $C_L$  = output load capacitance in pF;  
 $V_{CC}$  = supply voltage in V;  
 $N$  = number of inputs switching;  
 $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

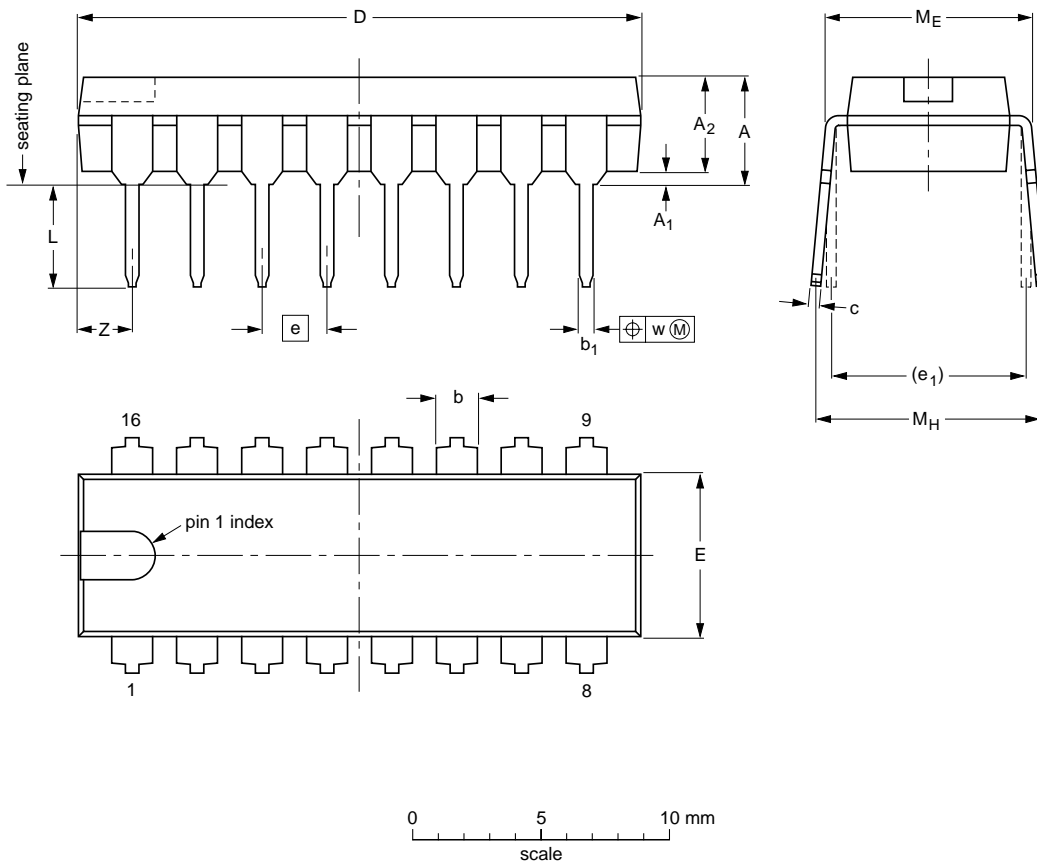
## 12. Waveforms



13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil); long body

SOT38-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	M <sub>E</sub>	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.7	0.51	3.7	1.40 1.14	0.53 0.38	0.32 0.23	21.8 21.4	6.48 6.20	2.54	7.62	3.9 3.4	8.25 7.80	9.5 8.3	0.254	2.2
inches	0.19	0.02	0.15	0.055 0.045	0.021 0.015	0.013 0.009	0.86 0.84	0.26 0.24	0.1	0.3	0.15 0.13	0.32 0.31	0.37 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION
	IEC	JEDEC	JEITA	
SOT38-1	050G09	MO-001	SC-503-16	

Fig 9. Package outline SOT38-1 (DIP16)